

Technical Data Data Sheet N2446, Rev.-



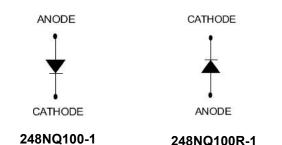
248NQ100/R-1 SCHOTTKY RECTIFIER



Features

- 175℃ T_J operation
- Unique high power, Half-Pak module
- Replaces three parallel DO-5' S
- Easier to mount and lower profile than DO-5' S
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Base plate: Nickel plated; Terminals: Nickel plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot •
- Additional testing can be offered upon request

Circuit Diagram



The top side is terminal, the bottom side is base plate.

Applications

- Switching power supply
- Converters
- **Free-Wheeling diodes**
- **Reverse battery protection**

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)					
Characteristics	Symbol	Condition		Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} VR	-		100	V
Average Forward Current	I _{F(AV)}	50% duty cycle $@T_c = 120$ °C, rectangular wave form		240	A
	I _{FSM}	8.3 ms, half Sine pulse		3960	A
Maximum Peak One Cycle Non- Repetitive Surge Current		5 us sine or 3 us rect. pulse	Following and rated load	25500	A
		10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	3300	
Non-Repetitive Avalanche Energy	E _{AS}	T _J =25°C,I _{AS} =1A,L=30 mH		15	mJ
Repetitive Avalanche Current	I _{AR}	Current decaying linearly to zero in 1 μsec Frequency limited by T_J max. V_A=1.5 \times V_R typical		1	А

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RoHS

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Electrical Characteristics:					
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 240A, Pulse, T _J = 25 °C	0.77	0.95	V
	V _{F2}	@ 240A, Pulse, T _J = 125 °C	0.62	0.72	V
Reverse Current*	I _{R1}	$@V_R = rated V_R T_J = 25 °C$	0.032	6	mA
	I _{R2}	@V _R = rated V _R T _J = 125 °C	12	80	mA
Junction Capacitance	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	5277	5500	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 μ s, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units
Junction Temperature	TJ	-	-55 to +175		°C
Storage Temperature	T _{stg}	-	-55 to	+175	°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	0.2	25	°C/W
Typical Thermal Resistance, case to Heat Sink	$R_{\theta cs}$	Mounting surface, smooth and greased	0.07		°C/W
Mounting Torque	т	T_M Non-lubricated threads	Mounting Torque	23(min) 29(max)	Ka am
	IM		Terminal Torque	35(min) 46(max)	Kg-cm
Approximate Weight	wt	-	36 g		g
Case Style	PRM1-1				

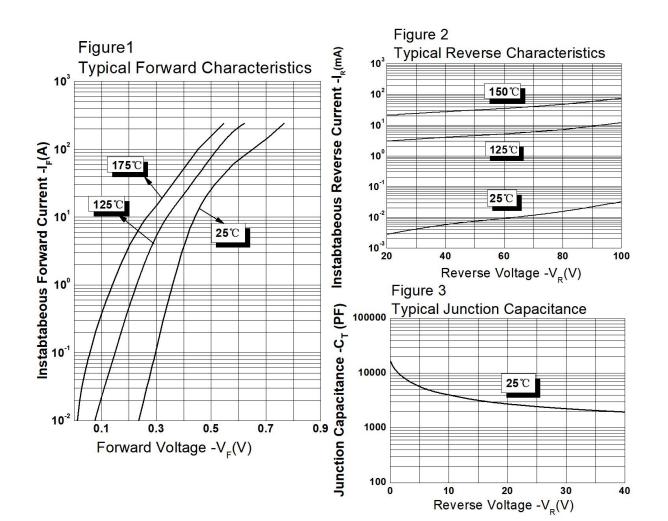
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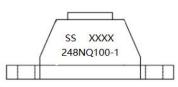
Ratings and Characteristics Curves



Ordering Information

Device	Package	Shipping
248NQ100(R)-1	PRM1-1(Pb-Free)	27pcs/ box

Marking Diagram



Where XXXX is YYWW

1st row S	S YYWW
2nd row 2	248NQ100-1
SS	= SS
YY	= Year
WW	= Week

Cautions: Molding resin Epoxy resin UL:94V-0

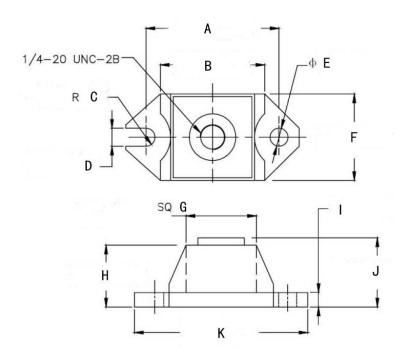
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Mechanical Dimensions PRM1-1 (Inches/Millimeters)

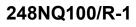


SYMBOL	Millimeters		Inches	
	Min.	Max.	Min.	Max.
А	29.35	30.95	1.155	1.219
В	24.77	26.04	0.975	1.026
С	1.79	2.19	0.070	0.087
D	3.73	4.24	0.146	0.167
E	3.73	4.24	0.146	0.167
F	18.42	19.69	0.725	0.775
G	18.55	19.55	0.730	0.770
Н	13.59	14.47	0.535	70.500
I	3.05	3.90	0.120	0.154
J	14.87	15.87	0.585	0.625
К	38.61	39.62	1.520	1.560

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